PATENT

5298-04100/PM00012

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Applicant:

Qiao et al.

Serial No. 09/661,666

Filed: September 14, 2000

Patent No. 6,803,318 Issued: October 12, 2004

For:

METHOD OF FORMING SELF

ALIGNED CONTACTS

Atty. Docket No. 5298-04100

Group Art Unit: 2813

I hereby certify that this correspondence is being deposited with the U.S. Postal Service as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313, on the date indicated below:

11/16/2004

1/16/2004 Date

TRANSMITTAL LETTER

§

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313

Dear Sir:

Certificate
NOV 3 0 2004
Of Correction

Transmitted herewith for filing in the captioned case are the following:

- (1) Form PTO-1050, **submitted in duplicate**. Errors which occur at important points in the captioned patent or which may otherwise affect the understanding or interpretation of the patent are thereon corrected.
- (2) A return postcard to acknowledge receipt of these materials. Please stamp and return this postcard to the undersigned.

All of the errors shown in PTO-1050 are due to Patent Office oversights. A Certificate of Correction is requested under 35 U.S.C. § 254. Applicants believe that no fees are required, however, should any fees be required, please deduct them from deposit account number 50-3268/5298-04100.

Respectfully submitted,

Keviń L. Daffer Reg. No. 34,146

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Date: November 16, 2004

UNITED STATES PATENT AND TRADEMARK OFFICE

CERTIFICATE OF CORRECTION

PATENT NO.

6,803,318

DATED:

October 12, 2004

INVENTOR(S): Qiao et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In the Claims:

1

Claim 1, col. 21, lines 57-58

Please delete "chemistries etch are" and substitute therefor "chemistries are--.

Claim 1, col. 21, line 59

Please delete "material silicon" and substitute therefor --material:silicon--.

Claim 8, col. 22, line 27

Please delete "he second" and substitute therefor -- the second--.

Claim 16, col. 22, line 56

Please delete "step or" and substitute therefor --step of--.

MAILING ADDRESS OF SENDER: Kevin L. Daffer, Esq., DAFFER McDANIEL, LLP P.O. Box 684908 Austin, TX 78768-4908

PATENT NO. 6,803,318

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UNITED STATES PATENT AND TRADEMARK OFFICE

CERTIFICATE OF CORRECTION

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DATED:

October 12, 2004

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